





Modelling the influence of clustered defects on HCF properties of Ni-based superalloys

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Preliminary results







Clustered defects

Introduction

Feature variable

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Kitagawa- Takahashi diagram: Fatigue life vs defect size





Introduction: Global strategy



Monte-Carlo Approach



Numerical simulations followed by statistical analysis



Estimate influence of defect characteristics on HCF



Develop a model on the basis of statistics of defects, CND criterions via a probabilistic approach



Image-based FE model to estimate fatigue life

Experimental campaign



Material: Inconel 100 Test temperature: 750 °C Load ratio: R = 0 Grains: Equiaxed

N°	Grade	Classe ressuage	Cycles	Crack-intiation site	
А	Grade 5	Classe <10	8 096	Interne	
В	Grade 5	Classe <10	77 155	Interne	
С	Grade 6	Classe <10	39 638	Subsurfacique	
D	Grade 6	Classe 20	31 343	Débouchante	



All samples failed in the zone of clustered defects due to one critical defect



SAFRAN



Image-based FE model to estimate fatigue life

Experimental campaign

Numerical campaign



SAFRAN



SAFRAN



-> Synthetic Microstructures

Preliminary results







Generative Adversarial Networks

Functionalities

- Generation of data that resembles the real data
- Image transformation from • one dimension to other





Generative Adversarial Networks

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 $\min_{G} \max_{D} V(D,G) = \min_{G} \max_{D} (\mathbb{E}_{x} [\log(D(x))] + \mathbb{E}_{z} [\log(1 - D(G(z)))]$



Generative Adversarial Networks





Generative Adversarial Networks: Loss history



Modifications – GAN :-

- One sided label smoothing addition of noise to labels
- Generator trained k times than discriminator to maintain balance between D and G



Generative Adversarial Networks: Examples





Spatial point pattern (SPP) Analysis

Ripley's K-function :-

K-function

Second order moment function that includes all distance pairs in a spatial pattern

 $K(d) = \lambda^{-1} E$ (number of points within distance d of a single arbitrary event)

Where λ →intensity or mean number of events in unit space In 3-D λ = Number of points / Volume E → Expected number of events in a length r K(d) → K-function

Sample A 14 Sample B Sample C 12 Sample D 6 Poisson process 10 5 The states are K function 8 6 3 4 2 2 1 0 0 0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 0 distance (mm)

Compare spatial pattern analysis with poisson process to investigate local clustering

Equation :-



Where, N \rightarrow Number of points $I \rightarrow \begin{cases} 1, & \text{if } r_{ij} < d \\ 0, & \text{otherwise} \end{cases}$



Expected number of points





SPP Analysis: Neyman Scott Process



- \Rightarrow Parent defect (type 1)
- \Leftrightarrow \rightarrow Child defect (type 2)



SPP Analysis: Neyman Scott Process



Ripley's K function for
two types of defect given as *K*₁₁ and *K*₂₂

 $K_{12}(d) = (\lambda_1 \lambda_2 V)^{-1} \sum_{i=1}^{N_1} \sum_{j=1}^{N_2} I(r_{ij} < d)$

Interaction between two processes : Cross K-function

Where, λ_1 and λ_2 are intensities of type 1 and 2 N1 and N2 are number of points of type 1 and 2

Bivariate K-function

 $K(r) = \begin{bmatrix} K_{11} & K_{12} \\ K_{21} & K_{22} \end{bmatrix}$

Introduction of parameter θ

- θ corresponds to defect size.
- Defects are classified with respect to θ as either type 1 or type 2
- For e.g., if $\theta == 0.6$ mm, all defects with size below θ belongs to type 1 and the rest type 2.



Spatial point pattern Analysis



- Clustering pattern observed in all samples
- In-homogenous process required for generation



- Defects larger than 0.6 mm are added first
- Defects smaller than 0.6 mm are added around larger defects – Neyman-Scott process







Other defects have

no influence on crack-initiation life



COMPLETE CHAIN







Examples



b) Real microstructure



Synthetic microstructure – Global statistical validation and comparison

Sphericity vs Aspect ratio



Spatial point pattern : cross K-function





Synthetic microstructure – Global statistical validation and comparison

Defect size distribution for 5 synthetic microstructure





PCC of synthetic and real microstructure



Synthetic







For each synthetic sample, the defect size distribution changes as per shape parameter

Generalized extreme value distribution:

 $Gev = e^{-(1-cx)^{1/c}}(1-cx)^{1/(c-1)}$

 $c \rightarrow$ Shape parameter

C depends on number of defects of respective sample







For each synthetic sample, the defect size distribution changes as per shape parameter

Total volume of cluster of generated samples

 $o \rightarrow$ Synthetic samples

Generalized extreme value distribution: $(1 - ar)^{1/c}$

 $Gev = e^{-(1-cx)^{1/c}}(1-cx)^{1/(c-1)}$

 $c \rightarrow$ Shape parameter

C depends on number of defects of respective sample







Preliminary numerical results







Number of cycles to failure: Numerical vs experimental correlation

Dissipated plastic strain energy per cycle

 $\Delta W_p = A(N)^k$ where A and k are constants.

Underlying assumptions of the criteria being: The crack is initiated on a defect with maximum dissipation at stabilized stress loop **Ref:** V. Maurel et al (2009)

Volumetric homogenization

$$\Delta W_{p,avg} = \frac{1}{V} \int_{V} \Delta W_{p}. \, dV$$





Number of cycles to failure: Numerical vs experimental correlation

Dissipated plastic strain energy per cycle

 $\Delta W_p = A(N)^k$

where A and k are constants.

Underlying assumptions of the criteria being: The crack is initiated on a defect with maximum dissipation at stabilized stress loop

Radius of 150 µm was chosen for stress homogenization after comparison with experimental results





Fit to experimental results to find parameters A and k

Α	k
147.49	-0.813

Prediction of number of cycles to failure



Failure criterion - Estimations



Wohler curve for different defect sizes

Defect size C > B > A i.e., fatigue limit decreases with respect to defect size

Relationship between fatigue limit and defect size:-

$$\sigma_D = \frac{C(H_v + 120)}{\sqrt{Area}^{1/6}} (\frac{1-R}{2})^{\alpha}$$

Where, Hv is the Vickers hardness, R the load ratio, \sqrt{Area} size of defect and σ_D , the fatigue limit

C = 1.56 for internal defect and 1.43 for surface defect.







Synthetic samples – Simulations

From fatigue reduction factor like SCF:

• Fatigue reduction factors from the experiments can be defined as,

$$\alpha_{f} = \frac{\sigma_{amp,healthy} |@ N cycles}{\sigma_{amp,samples} |@ N cycles}$$

$$\sigma_D = \frac{\sigma_{D,healthy}}{K_f}$$

• Fatigue limit reduces as much as k_f





Fit an exponential law for number of cycles to failure – **Basquin law**

$$\frac{\sigma}{\sigma_D} = C * (N)^b$$



Synthetic samples – Simulations

Assuming Fatigue reduction factor == Stress concentration factor, As in the case of notches



Stress concentration factor measured as,

$$K_t = \frac{\sigma_{local}}{\sigma_{nominal}}$$







Synthetic samples – Simulations

Assuming Fatigue reduction factor == Stress concentration factor, As in the case of notches







Introduction

Preliminary numerical results









Conclusions and perspectives

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- Samples of IN100 fail at the zone of clustered defects
- Synthetic microstructures can exactly mimic real samples and can be used to create a large database of mechanical response
- It is possible to generate synthetic microstructure of particular ASTM grade
- The cluster volume has a direct influence on fatigue due to high probability of large defects in the cluster
- An analysis similar to sensitivity analysis can be done using synthetic microstructure to estimate influence of cluster volume, thickness etc on stress gradients
- Monte carlo kind of approach to predict probable fatigue life based on cluster characteristics
- Experimental tests of more samples to estimate crack initiation





Merci!! Thank you for your attention







Back-ups







Volume of defects larger than 0.6mm is specific to ASTM grade.

Hence a fit is constrained here on the volume of defects

















ASTM Grade – Synthetic samples

Sample	Area (in mm2)	Volume of defects in cluster	Number of defects	/
Grade 5	1.47			
2L1	1.0	0.48	48	/ /
2P1	1.2	0.55	88	
Grade 6	2.21			
2R1	2.99	0.88	64	
2S1	1.98	0.76	118	

Less number of defects but more larger defects

- Two different distributions for each grade
- By constraining volume and using respective distribution of ASTM grade, synthetic samples respecting grades are generated

More number of defects but less larger defects





PSL 🔀 **MINES PARIS**

Beer-Lambert Law of X-ray intensity :



For small discretized thickness dx, $I = constant * \int_0^L dx$ $L \rightarrow$ Length of the material $I \rightarrow$ Intensity

 $I = constant * \sum_{k=1}^{L} dx$

Image of sample

Summation in direction perpendicular to axis for Radiography

Virtual Radiography





ASTM norm 1/8 in (3mm) – Spongeous Shrinkage

- Homogeneous Radiography examples for a thickness of 3mm and can be applied for a thickness of upto 6mm
- Image resolution of 100µm
- Different greyscale intensity





- Apply correction factor to transfer cylinder into a plate
- Resize as per the resolution of ASTM examples
- Greyscale intensity matching by Boolean operations







ASTM grade - Prediction

Shannon entropy: -

$$H(X) = -\sum_{x \in X} p(x) log_b(x)$$

 $X \rightarrow$ Image

 $x \rightarrow$ each greyscale value between 0-255









100

grey value

80

120

140

Entropy = 5.5

60

40



Max entropy @ uniform distribution = 8.0

ASTM grade - Prediction





ASTM grade - Prediction

Multiple iterations needed so that the measurements are constant

B5

B4

Perfect predictions for all samples except one

Fatigue Reduction factor

- Fatigue reduction factors from the experiments can be defined as, $k_f = \frac{\sigma_{amp,healthy} |@ \ N \ cycles}{\sigma_{amp,samples} |@ \ N \ cycles}$
 - Fatigue limit reduces as much as k_f

• By numerical approach, stress concentration factors are the fatigue reduction factors such that, $\sigma_{D} = \frac{\sigma_{D,healthy}}{\sigma_{D}}$

$$\overline{k_D} = \frac{1}{k_{t,critical}}$$

With the assumption that, $k_t = k_f$

Ref: Matpadi Raghavendra et al (2022)

